

3 Watt Cellular T/R and Antenna Changeover Switch DC - 3.0 GHz

Rev. V5

Features

- Low Cost Plastic SOT-26 Package
- Low Insertion Loss: < 0.6 dB @ 1900 MHz
- Low Power Consumption: <20µA @ +3V
- Very High Intercept Point: 53 dBm IP3
- Both Positive and Negative 2.5 to 8 V Control
- For CDMA, W-CDMA, TDMA, GSM, PCS and **DCS** Applications

Description

M/A-COM's SW-425 is a GaAs monolithic switch in a low cost SOT-26 surface mount plastic package. The SW-425 is ideally suited for applications where very low consumption $(<10 \mu A @ 5V)$, intermodulation products and very small size are required. Typical applications include Internal/External antenna select switch for portable telephones and data radios. In addition, because of its low loss, good isolation and inherent speed, the SW-425 can be used as a conventional T/R switch or as an antenna diversity switch. The SW-425 can be used in power applications up to 3 watts in systems such as cellular PCS, CDMA, W-CDMA, TDMA, GSM and other analog/digital wireless communications systems.

The SW-425 is fabricated using M/A-COM's 0.5 micron gate length GaAs PHEMT process. The process features full chip passivation for increased performance and reliability.

Ordering Information¹

| Part Number | Package | | |
|-------------|-----------------|--|--|
| SW-425 PIN | Bulk Packaging | | |
| SW-425TR | 1000 piece reel | | |

^{1.} Reference Application Note M513 for reel size information.

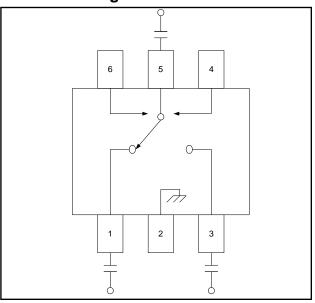
Absolute Maximum Ratings²

Commitment to produce in volume is not guaranteed.

| Parameter | Absolute Maximum | | |
|---|--------------------|--|--|
| Input Power (0.5—3.0 GHz) 3 V Control 5 V Control | +36 dBm +38 dBm | | |
| Operating Temperature | -40°C to +85°C | | |
| Storage Temperature | -65°C to +150°C | | |

^{2.} Exceeding any one or combination of these limits may cause permanent damage to this device.

Functional Diagram



Pin Configuration

| Pin No. | Function | Pin No. | Function |
|---------|----------|---------|-----------|
| 1 | RF1 | 4 | VB |
| 2 | Ground | 5 | RF Common |
| 3 | RF2 | 6 | VA |

Truth Table

| Mode (Control) | Control A | Control B | RFC - RF1 | RFC - RF2 |
|-------------------------|--------------------|--------------------|--------------|--------------|
| Positive ⁴ | 0 <u>+</u> 0.2 V | +2.5 to +8 V | Off | On |
| | +2.5 to +8 V | 0 <u>+</u> 0.2 V | On | Off |
| Positive/ | -Vc <u>+</u> 0.2 V | +Vc | Off | On |
| Negative ^{3,4} | +Vc | -Vc <u>+</u> 0.2 V | On | Off |
| Negative ⁵ | 0 ± 0.2 V | -2.5 to -8 V | On | Off |
| | -2.5 to -8 V | 0 <u>+</u> 0.2 V | Off | On |

- 3. External DC blocking capacitors are required on all RF ports. 39 pF capacitors can be used for positive control voltage.
- 4. [-VCTL], VCTL < 8 V
- 5. If negative control is used, DC blocking capacitors are not required on RF ports.

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[•] China Tel: +86.21.2407.1588



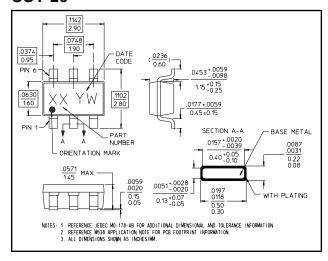
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Electrical Specifications: $T_A = +25$ °C

| Parameter | Test Conditions | | Min | Тур | Max |
|----------------------|---|--|----------------|--------------------|--------------------|
| Insertion Loss | DC - 1 GHz 1 - 2 GHz 2 - 3 GHz | | | 0.4 0.55 0.7 | 0.5 0.65 0.8 |
| Isolation | DC - 1 GHz 1 - 2 GHz 2 - 3 GHz | | 18 13 10 | 20 15 12 | |
| VSWR | DC - 3 GHz | | | 1.2:1 | 1.4:1 |
| P1dB (3 V supply) | 500 MHz - 3 GHz | | 32 | 34 | _ |
| P1dB (5 V supply) | 500 MHz - 3 GHz | | 34 | 36 | _ |
| Input IP2 | Two-Tone, 5 MHz spacing, +10 dBm (+13 dBm total) $V_{CTL} = 3 V$ 0.9 GHz | | 62 | 70 | _ |
| Input IP3 | Two-Tone, 5 MHz spacing, +10 dBm (+13 dBm total) V _{CTL} = 3 V 0.9 GHz | | 48 | 53 | _ |
| 2nd Harmonics | Pin 30 dBm [V_{CTL}] = 3 V Pin 33 dBm [V_{CTL}] = 5 V | | 65 65 | 70 75 | _ |
| 3rd Harmonics | Pin 30 dBm [V_{CTL}] = 3 V Pin 33 dBm [V_{CTL}] = 5 V | | 45 65 | 48 75 | _ |
| Trise, Tfall | 10% to 90% RF, 90% to 10% RF | | _ | 60 | _ |
| Ton, Toff | 50% Control to 90% RF, Control to 10% RF | | _ | 20 | _ |
| Transients | In-Band | | | 20 | |
| Gate Leakage Current | V _{CTL} = 3 V | | _ | 10 | 20 |

SOT-26



Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

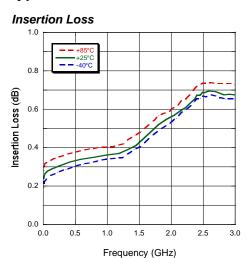
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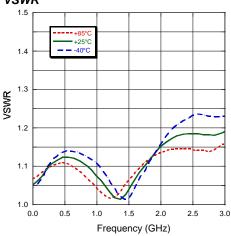
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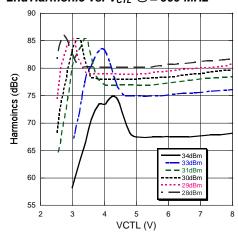
Typical Performance Curves



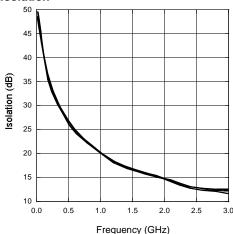
VSWR



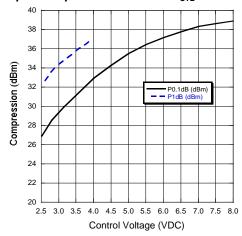
2nd Harmonic vs. V_{CTL} @ = 900 MHz



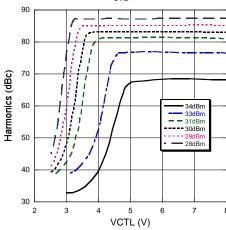
Isolation



Input Compression Point vs. V_{CTL} @ 900 MHz



3rd Harmonic vs. V_{CTL} @ = 900 MHz



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• North America Tel: 800.366.2266 • Europe Tel: +353.21.244.6400

• India Tel: +91.80.43537383 Visit www.macomtech.com for additional data sheets and product information.

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